NSN 5962-01-266-3206

Memory Microcircuit - Page 1 of 1



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Features Provided:
Erasable and programmable and positive outputs
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Criticality Code Justification:
Feat
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Time Rating Per Chacteristic:
300.00 nanoseconds propagation delay time, low to high level output and 300.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Special Features:
Item must comply with requirements of defense electronics supply center production standard no. L03871; for navy nuclear propulsion plan
products only
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
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